

S34MS01G200BHB003

S34MS01G200BHB003 Information

Heisener.com	 S34MS01G200BHB003 Cypress Semiconductor Corp Integrated Circuits (ICs) Memory NAND - For the pricing/inventory/lead time, please contact	
For Reference Only	us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



S34MS01G200BHB003 Specifications

Manufacturer Part Number	S34MS01G200BHB003
Manufacturer	Cypress Semiconductor Corp
Category	Integrated Circuits (ICs)
	Memory
Package	-
Series	Automotive, AEC-Q100, MS-2
Memory Type	Non-Volatile
Memory Format	FLASH
Technology	FLASH - NAND
Memory Size	1Gb (128M x 8)
Memory Interface	Parallel
Clock Frequency	-
Write Cycle Time - Word, Page	45ns
Access Time	45ns
Voltage - Supply	1.7 V ~ 1.95 V
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	-
Package / Case	-
Supplier Device Package	-
	Report errors?

S34MS01G200BHB003 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE BUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

S34MS01G200BHB003 Payment Methods



If you have any question about S34MS01G200BHB003, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com